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Applications of "<u>Embedded -</u> <u>Microcontrollers</u>"

Details

Product Status	Active
Core Processor	PIC
Core Size	8-Bit
Speed	4MHz
Connectivity	-
Peripherals	POR, WDT
Number of I/O	12
Program Memory Size	768B (512 x 12)
Program Memory Type	ОТР
EEPROM Size	-
RAM Size	25 x 8
Voltage - Supply (Vcc/Vdd)	3V ~ 6.25V
Data Converters	-
Oscillator Type	External
Operating Temperature	0°C ~ 70°C (TA)
Mounting Type	Surface Mount
Package / Case	20-SSOP (0.209", 5.30mm Width)
Supplier Device Package	20-SSOP
Purchase URL	https://www.e-xfl.com/product-detail/microchip-technology/pic16c54-xt-ss

Email: info@E-XFL.COM

Address: Room A, 16/F, Full Win Commercial Centre, 573 Nathan Road, Mongkok, Hong Kong

Pin Diagrams



Device Differences

Device	Voltage Range	Oscillator Selection (Program)	Oscillator	Process Technology (Microns)	ROM Equivalent	MCLR Filter
PIC16C54	2.5-6.25	Factory	See Note 1	1.2	PIC16CR54A	No
PIC16C54A	2.0-6.25	User	See Note 1	0.9	—	No
PIC16C54C	2.5-5.5	User	See Note 1	0.7	PIC16CR54C	Yes
PIC16C55	2.5-6.25	Factory	See Note 1	1.7	—	No
PIC16C55A	2.5-5.5	User	See Note 1	0.7	—	Yes
PIC16C56	2.5-6.25	Factory	See Note 1	1.7	—	No
PIC16C56A	2.5-5.5	User	See Note 1	0.7	PIC16CR56A	Yes
PIC16C57	2.5-6.25	Factory	See Note 1	1.2	—	No
PIC16C57C	2.5-5.5	User	See Note 1	0.7	PIC16CR57C	Yes
PIC16C58B	2.5-5.5	User	See Note 1	0.7	PIC16CR58B	Yes
PIC16CR54A	2.5-6.25	Factory	See Note 1	1.2	N/A	Yes
PIC16CR54C	2.5-5.5	Factory	See Note 1	0.7	N/A	Yes
PIC16CR56A	2.5-5.5	Factory	See Note 1	0.7	N/A	Yes
PIC16CR57C	2.5-5.5	Factory	See Note 1	0.7	N/A	Yes
PIC16CR58B	2.5-5.5	Factory	See Note 1	0.7	N/A	Yes

Note 1: If you change from this device to another device, please verify oscillator characteristics in your application.

Note: The table shown above shows the generic names of the PIC16C5X devices. For device varieties, please refer to Section 2.0.

4.0 OSCILLATOR CONFIGURATIONS

4.1 Oscillator Types

PIC16C5Xs can be operated in four different oscillator modes. The user can program two configuration bits (FOSC1:FOSC0) to select one of these four modes:

- 1. LP: Low Power Crystal
- 2. XT: Crystal/Resonator
- 3. HS: High Speed Crystal/Resonator
- 4. RC: Resistor/Capacitor

Note: Not all oscillator selections available for all parts. See Section 9.1.

4.2 Crystal Oscillator/Ceramic Resonators

In XT, LP or HS modes, a crystal or ceramic resonator is connected to the OSC1/CLKIN and OSC2/CLKOUT pins to establish oscillation (Figure 4-1). The PIC16C5X oscillator design requires the use of a parallel cut crystal. Use of a series cut crystal may give a frequency out of the crystal manufacturers specifications. When in XT, LP or HS modes, the device can have an external clock source drive the OSC1/CLKIN pin (Figure 4-2).

FIGURE 4-1: CRYSTAL/CERAMIC RESONATOR OPERATION (HS, XT OR LP OSC CONFIGURATION)



FIGURE 4-2:

EXTERNAL CLOCK INPUT OPERATION (HS, XT OR LP OSC CONFIGURATION)



TABLE 4-1: CAPACITOR SELECTION FOR CERAMIC RESONATORS -PIC16C5X, PIC16CR5X

Osc Type	Resonator Freq	Cap. Range C1	Cap. Range C2
XT	455 kHz	68-100 pF	68-100 pF
	2.0 MHz	15-33 pF	15-33 pF
	4.0 MHz	10-22 pF	10-22 pF
HS	8.0 MHz	10-22 pF	10-22 pF
	16.0 MHz	10 pF	10 pF

These values are for design guidance only. Since each resonator has its own characteristics, the user should consult the resonator manufacturer for appropriate values of external components.

TABLE 4-2: CAPACITOR SELECTION FOR CRYSTAL OSCILLATOR -PIC16C5X. PIC16CR5X

	,					
Osc Type	Crystal Freq	Cap.Range C1	Cap. Range C2			
LP	32 kHz ⁽¹⁾	15 pF	15 pF			
XT	100 kHz	15-30 pF	200-300 pF			
	200 kHz	15-30 pF	100-200 pF			
	455 kHz	15-30 pF	15-100 pF			
	1 MHz	15-30 pF	15-30 pF			
	2 MHz	15 pF	15 pF			
	4 MHz	15 pF	15 pF			
HS	4 MHz	15 pF	15 pF			
	8 MHz	15 pF	15 pF			
	20 MHz	15 pF	15 pF			

Note 1: For VDD > 4.5V, C1 = C2 \approx 30 pF is recommended.

These values are for design guidance only. Rs may be required in HS mode as well as XT mode to avoid overdriving crystals with low drive level specification. Since each crystal has its own characteristics, the user should consult the crystal manufacturer for appropriate values of external components.

Note: If you change from this device to another device, please verify oscillator characteristics in your application.

NOTES:

9.3 Power-Down Mode (SLEEP)

A device may be powered down (SLEEP) and later powered up (Wake-up from SLEEP).

9.3.1 SLEEP

The Power-down mode is entered by executing a SLEEP instruction.

If enabled, the Watchdog Timer will be cleared but keeps running, the TO bit (STATUS<4>) is set, the PD bit (STATUS<3>) is cleared and the oscillator driver is turned off. The I/O ports maintain the status they had before the SLEEP instruction was executed (driving high, driving low, or hi-impedance).

It should be noted that a RESET generated by a WDT time-out does not drive the MCLR/VPP pin low.

For lowest current consumption while powered down, the T0CKI input should be at VDD or Vss and the $\overline{\text{MCLR}}/\text{VPP}$ pin must be at a logic high level ($\overline{\text{MCLR}}$ = VIH).

9.3.2 WAKE-UP FROM SLEEP

The device can wake up from SLEEP through one of the following events:

- 1. An external RESET input on MCLR/VPP pin.
- 2. A Watchdog Timer Time-out Reset (if WDT was enabled).

Both of these events cause a device RESET. The $\overline{\text{TO}}$ and $\overline{\text{PD}}$ bits can be used to determine the cause of device RESET. The $\overline{\text{TO}}$ bit is cleared if a WDT timeout occurred (and caused wake-up). The $\overline{\text{PD}}$ bit, which is set on power-up, is cleared when SLEEP is invoked.

The WDT is cleared when the device wakes from SLEEP, regardless of the wake-up source.

9.4 Program Verification/Code Protection

If the code protection bit(s) have not been programmed, the on-chip program memory can be read out for verification purposes.

Note:	Microchip does not recommend code pro-
	tecting windowed devices.

9.5 ID Locations

Four memory locations are designated as ID locations where the user can store checksum or other code-identification numbers. These locations are not accessible during normal execution but are readable and writable during program/verify.

Use only the lower 4 bits of the ID locations and always program the upper 8 bits as '1's.

Note: Microchip will assign a unique pattern number for QTP and SQTP requests and for ROM devices. This pattern number will be unique and traceable to the submitted code.

ADDWF	Add W	and f		
Syntax:	[label] A	DDWF	f,d	
Operands:	$\begin{array}{l} 0 \leq f \leq 31 \\ d \in [0,1] \end{array}$			
Operation:	$(W) + (f) \to (dest)$			
Status Affected:	C, DC, Z			
Encoding:	0001	11df	ffff	
Description:	Add the contents of the W register and register 'f'. If 'd' is 0 the result is stored in the W register. If 'd' is '1' the result is stored back in register 'f'.			
Words:	1			
Cycles:	1			
Example:	ADDWF	TEMP_RE	G, 0	
Before Instr W TEMP_I After Instruc W TEMP_F	= REG = ction =	0x17 0xC2 0xD9 0xC2		

ANDWF	AND W with f			
Syntax:	[label] ANDWF f,d			
Operands:	$\begin{array}{l} 0 \leq f \leq 31 \\ d \in [0,1] \end{array}$			
Operation:	(W) .AND. (f) \rightarrow (dest)			
Status Affected:	Z			
Encoding:	0001 01df ffff			
Description:	The contents of the W register are AND'ed with register 'f'. If 'd' is 0 the result is stored in the W regis- ter. If 'd' is '1' the result is stored back in register 'f'.			
Words:	1			
Cycles:	1			
Example:	ANDWF TEMP_REG, 1			
Before Instru W TEMP_ After Instruc W TEMP_	= 0x17 REG = 0xC2 tion = 0x17			

ANDLW	AND literal with W			
Syntax:	[<i>label</i>] ANDLW k			
Operands:	$0 \le k \le 255$			
Operation:	(W).AND. (k) \rightarrow (W)			
Status Affected:	Z			
Encoding:	1110 kkkk kkkk			
Description:	The contents of the W register are AND'ed with the eight-bit literal 'k'. The result is placed in the W regis- ter.			
Words:	1			
Cycles:	1			
Example:	ANDLW H'5F'			
Before Instru W = After Instruc W =	0xA3			

BCF	Bit Clea	r f			
Syntax:	[label]	BCF f,ł)		
Operands:	$\begin{array}{l} 0 \leq f \leq 3^{\prime} \\ 0 \leq b \leq 7 \end{array}$	-			
Operation:	$0 \rightarrow (f < b >)$				
Status Affected:	None				
Encoding:	0100	bbbf	ffff		
Description:	Bit 'b' in	register 'f'	is cleared.		
Words:	1				
Cycles:	1				
Example:	BCF	FLAG_RE	IG, 7		
Before Instruction FLAG_REG = 0xC7 After Instruction					
FLAG_F	REG =	0x47			

TABLE 11-1: DEVELOPMENT TOOLS FROM MICROCHIP

	- - - -	6 33 520 540 540 540 540 540 540 540 540 540 54	мсь мс <i>в</i>
MPLAB [®] C17 C complex I	> > > >	>	
MPLAB [®] C18 C compiler I		· · ·	
MPASN™ Assembler/ MPLNW™ Object Linker ×		× ×	
MPLAB® (CE In-Circuit Emulator	> > > >	> > > >	×
ICEPIC ^M In-Circuit Emulator ✓ <t< th=""><th>× × ×</th><th></th><th></th></t<>	× × ×		
MPLAB® ICD In-Circuit ·· </th <th>></th> <th></th> <th></th>	>		
PICSTART® Plus Entry Level <th< th=""><th></th><th>></th><th></th></th<>		>	
PRO MATE® II · · · · · · · · · · · · · · · · · · ·	> > >	> >	
PICDEMTW 1 Demonstration <	> > >	> > > >	`
PICDEMTW 2 Demonstration	>		
PICDEMTW 3 Demonstration PICDEMTW 3 Demonstration PICDEMTW 14A Demonstration PIC	×+	>	
PICDEM TM 14A Demonstration Board PICDEM TM 17 Demonstration Board KEELoa [®] Evaluation Kit KEELoa [®] Transponder Kit microlD TM Programmer's Kit 125 KHz microlD TM	*		
		>	
			
			>
			>
Developer's Kit			>
125 kHz Anticollision microlD TM Developer's Kit			>
13.56 MHz Anticollision microlD TM Developer's Kit			>
MCP2510 CAN Developer's Kit			×

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12.2 DC Characteristics: PIC16C54/55/56/57-RCI, XTI, 10I, HSI, LPI (Industrial)

PIC16C (Indust		57-RCI, XTI, 10I, HSI, LPI					(unless otherwise specified) TA \leq +85°C for industrial
Param No.	Symbol	Characteristic/Device	Min	Тур†	Max	Units	Conditions
D001	Vdd	Supply Voltage PIC16C5X-RCI PIC16C5X-XTI PIC16C5X-10I PIC16C5X-HSI PIC16C5X-LPI	3.0 3.0 4.5 4.5 2.5		6.25 6.25 5.5 5.5 6.25	V V V V	
D002	Vdr	RAM Data Retention Voltage ⁽¹⁾		1.5*		V	Device in SLEEP mode
D003	VPOR	VDD Start Voltage to ensure Power-on Reset	—	Vss	—	V	See Section 5.1 for details on Power-on Reset
D004	SVDD	VDD Rise Rate to ensure Power-on Reset	0.05*		—	V/ms	See Section 5.1 for details on Power-on Reset
D010	IDD	Supply Current ⁽²⁾ PIC16C5X-RCI ⁽³⁾ PIC16C5X-XTI PIC16C5X-10I PIC16C5X-HSI PIC16C5X-HSI PIC16C5X-LPI		1.8 1.8 4.8 4.8 9.0 15	3.3 3.3 10 10 20 40	mA mA mA mA μA	Fosc = 4 MHz, VDD = $5.5V$ Fosc = 4 MHz, VDD = $5.5V$ Fosc = 10 MHz, VDD = $5.5V$ Fosc = 10 MHz, VDD = $5.5V$ Fosc = 20 MHz, VDD = $5.5V$ Fosc = 32 kHz, VDD = $3.0V$, WDT disabled
D020	Ipd	Power-down Current ⁽²⁾	_	4.0 0.6	14 12	μΑ μΑ	VDD = 3.0V, WDT enabled VDD = 3.0V, WDT disabled

* These parameters are characterized but not tested.

- † Data in "Typ" column is based on characterization results at 25°C. This data is for design guidance only and is not tested.
- Note 1: This is the limit to which VDD can be lowered in SLEEP mode without losing RAM data.
 - 2: The supply current is mainly a function of the operating voltage and frequency. Other factors such as bus loading, oscillator type, bus rate, internal code execution pattern and temperature also have an impact on the current consumption.
 - a) The test conditions for all IDD measurements in active Operation mode are: OSC1 = external square wave, from rail-to-rail; all I/O pins tristated, pulled to Vss, T0CKI = VDD, MCLR = VDD; WDT enabled/disabled as specified.
 - b) For standby current measurements, the conditions are the same, except that the device is in SLEEP mode. The power-down current in SLEEP mode does not depend on the oscillator type.
 - **3:** Does not include current through REXT. The current through the resistor can be estimated by the formula: IR = VDD/2REXT (mA) with REXT in kΩ.

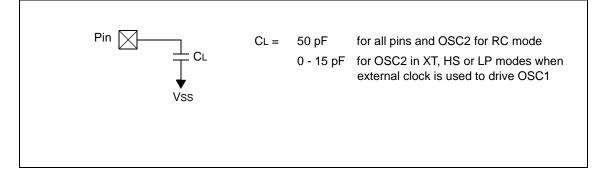
12.6 Timing Parameter Symbology and Load Conditions

The timing parameter symbols have been created with one of the following formats:

1. TppS2ppS

2. Tp	nS	
	PO	
Т		
F	Frequency	T Time
Lowe	ercase letters (pp) and their meanings:	
рр		
2	to	mc MCLR
ck	CLKOUT	osc oscillator
су	cycle time	os OSC1
drt	device reset timer	t0 T0CKI
io	I/O port	wdt watchdog timer
Uppe	ercase letters and their meanings:	
S		
F	Fall	P Period
Н	High	R Rise
I	Invalid (Hi-impedance)	V Valid
L	Low	Z Hi-impedance

FIGURE 12-1: LOAD CONDITIONS FOR DEVICE TIMING SPECIFICATIONS - PIC16C54/55/56/57



12.7 Timing Diagrams and Specifications

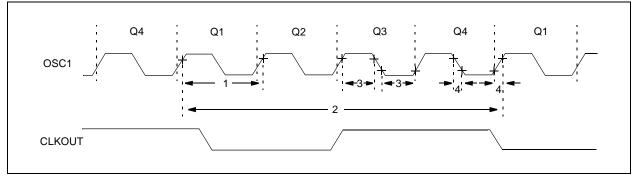


FIGURE 12-2: EXTERNAL CLOCK TIMING - PIC16C54/55/56/57

TABLE 12-1: EXTERNAL CLOCK TIMING REQUIREMENTS - PIC16C54/55/56/57

AC Characteristics							
Param No. Symbol		Characteristic	Min	Тур†	Max	Units	Conditions
1A	Fosc	External CLKIN Frequency ⁽¹⁾	DC		4.0	MHz	XT OSC mode
			DC	—	10	MHz	10 MHz mode
			DC	_	20	MHz	HS osc mode (Comm/Ind)
			DC	_	16	MHz	HS osc mode (Ext)
			DC	—	40	kHz	LP osc mode
		Oscillator Frequency ⁽¹⁾	DC	_	4.0	MHz	RC osc mode
			0.1	_	4.0	MHz	XT OSC mode
			4.0	_	10	MHz	10 MHz mode
			4.0	_	20	MHz	HS OSC mode (Comm/Ind)
			4.0	_	16	MHz	HS osc mode (Ext)
			DC	—	40	kHz	LP osc mode

* These parameters are characterized but not tested.

† Data in the Typical ("Typ") column is at 5.0V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.

Note 1: All specified values are based on characterization data for that particular oscillator type under standard operating conditions with the device executing code. Exceeding these specified limits may result in an unstable oscillator operation and/or higher than expected current consumption. When an external clock input is used, the "max" cycle time limit is "DC" (no clock) for all devices.

2: Instruction cycle period (TCY) equals four times the input oscillator time base period.

13.3 DC Characteristics: PIC16CR54A-04, 10, 20, PIC16LCR54A-04 (Commercial) PIC16CR54A-04I, 10I, 20I, PIC16LCR54A-04I (Industrial)

		$\begin{array}{llllllllllllllllllllllllllllllllllll$					
Param No.	Symbol	Characteristic	Min	Тур†	Max	Units	Conditions
D030	VIL	Input Low Voltage I/O ports MCLR (Schmitt Trigger) T0CKI (Schmitt Trigger) OSC1 (Schmitt Trigger) OSC1	Vss Vss Vss Vss Vss		0.2 VDD 0.15 VDD 0.15 VDD 0.15 VDD 0.15 VDD 0.15 VDD	V V V V	Pin at hi-impedance RC mode only ⁽³⁾ XT, HS and LP modes
D040	VIн	Input High Voltage I/O ports I/O ports MCLR (Schmitt Trigger) T0CKI (Schmitt Trigger) OSC1 (Schmitt Trigger) OSC1	2.0 0.6 VDD 0.85 VDD 0.85 VDD 0.85 VDD 0.85 VDD		VDD VDD VDD VDD VDD VDD VDD	V V V V V	VDD = 3.0V to 5.5V ⁽⁴⁾ Full VDD range ⁽⁴⁾ RC mode only ⁽³⁾ XT, HS and LP modes
D050	VHYS	Hysteresis of Schmitt Trigger inputs	0.15 VDD*	—	_	V	
D060	lι∟	Input Leakage Current ^(1,2) I/O ports	-1.0	_	+1.0	μA	For VDD \leq 5.5V: VSS \leq VPIN \leq VDD, pin at hi-impedance
		MCLR MCLR T0CKI OSC1	-5.0 -3.0 -3.0	— 0.5 0.5 0.5	 +5.0 +3.0 +3.0	μΑ μΑ μΑ	$\label{eq:VPIN} \begin{array}{l} VPIN = VSS + 0.25V \\ VPIN = VDD \\ VSS \leq VPIN \leq VDD \\ VSS \leq VPIN \leq VDD, \\ XT, HS \text{and} LP \text{modes} \end{array}$
D080	Vol	Output Low Voltage I/O ports OSC2/CLKOUT		_	0.5 0.5	V V	IOL = 10 mA, VDD = 6.0V IOL = 1.9 mA, VDD = 6.0V, RC mode only
D090	Vон	Output High Voltage ⁽²⁾ I/O ports OSC2/CLKOUT	Vdd - 0.5 Vdd - 0.5	_		V V	IOH = -4.0 mA, VDD = 6.0 V IOH = -0.8 mA, VDD = 6.0 V, RC mode only

* These parameters are characterized but not tested.

- † Data in the Typical ("Typ") column is based on characterization results at 25°C. This data is for design guidance only and is not tested.
- **Note 1:** The leakage current on the MCLR/VPP pin is strongly dependent on the applied voltage level. The specified levels represent normal operating conditions. Higher leakage current may be measured at different input voltage.
 - 2: Negative current is defined as coming out of the pin.
 - **3:** For the RC mode, the OSC1/CLKIN pin is a Schmitt Trigger input. It is not recommended that the PIC16C5X be driven with external clock in RC mode.
 - 4: The user may use the better of the two specifications.

14.0 DEVICE CHARACTERIZATION - PIC16C54A

The graphs and tables provided following this note are a statistical summary based on a limited number of samples and are provided for informational purposes only. The performance characteristics listed herein are not tested or guaranteed. In some graphs or tables, the data presented may be outside the specified operating range (e.g., outside specified power supply range) and therefore outside the warranted range.

"Typical" represents the mean of the distribution at 25°C. "Maximum" or "minimum" represents (mean + 3σ) or (mean - 3σ) respectively, where σ is a standard deviation, over the whole temperature range.



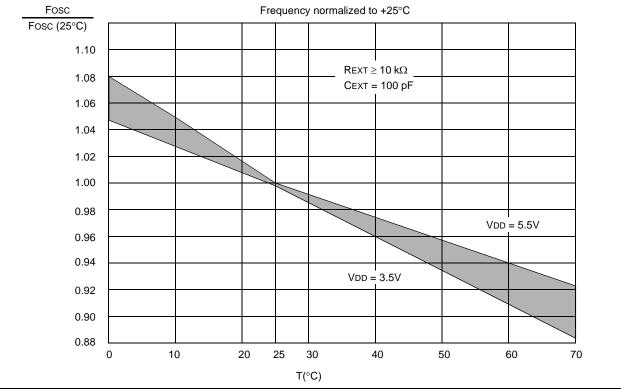


TABLE 14-1: RC OSCILLATOR FREQUENCIES

Сехт	Rext	Average Fosc @ 5 V, 25°C		
20 pF	3.3K	5 MHz	± 27%	
	5K	3.8 MHz	± 21%	
	10K	2.2 MHz	± 21%	
	100K	262 kHz	± 31%	
100 pF	3.3K	1.6 MHz	± 13%	
	5K	1.2 MHz	± 13%	
	10K	684 kHz	± 18%	
	100K	71 kHz	± 25%	
300 pF	3.3K	660 kHz	± 10%	
	5.0K	484 kHz	± 14%	
	10K	267 kHz	± 15%	
	100K	29 kHz	± 19%	

The frequencies are measured on DIP packages.

The percentage variation indicated here is part-to-part variation due to normal process distribution. The variation indicated is ± 3 standard deviations from the average value for VDD = 5V.

FIGURE 14-6: MAXIMUM IPD vs. VDD, WATCHDOG DISABLED

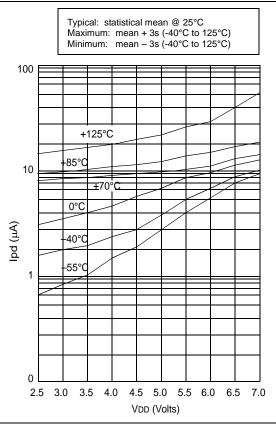


FIGURE 14-7: T

TYPICAL IPD vs. VDD, WATCHDOG ENABLED

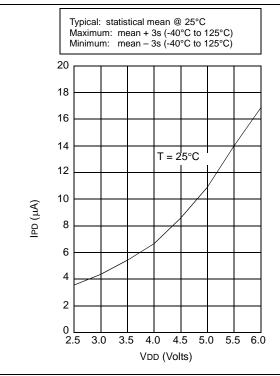
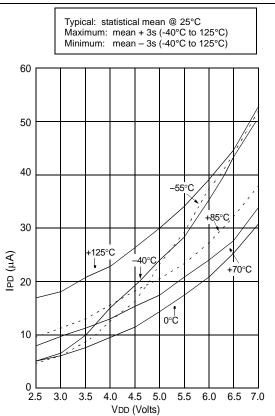


FIGURE 14-8: MAXIMUM IPD vs. VDD, WATCHDOG ENABLED



IPD, with WDT enabled, has two components: The leakage current, which increases with higher temperature, and the operating current of the WDT logic, which increases with lower temperature. At -40° C, the latter dominates explaining the apparently anomalous behavior.

15.4 DC Characteristics: PIC16C54A-04, 10, 20, PIC16LC54A-04, PIC16LV54A-02 (Commercial) PIC16C54A-04I, 10I, 20I, PIC16LC54A-04I, PIC16LV54A-02I (Industrial) PIC16C54A-04I, 10I, 20I, PIC16LC54A-04I, PIC16LV54A-02I (Industrial) PIC16C54A-04E, 10E, 20E, PIC16LC54A-04E (Extended)

			$ \begin{array}{l} \mbox{Standard Operating Conditions (unless otherwise specified)} \\ \mbox{Operating Temperature} & 0^{\circ}C \leq TA \leq +70^{\circ}C \mbox{ for commercial} \\ -40^{\circ}C \leq TA \leq +85^{\circ}C \mbox{ for industrial} \\ -20^{\circ}C \leq TA \leq +85^{\circ}C \mbox{ for industrial-PIC16LV54A-02I} \\ -40^{\circ}C \leq TA \leq +125^{\circ}C \mbox{ for extended} \end{array} $					
Param No.	Symbol	Characteristic	Min	Тур†	Мах	Units	Conditions	
D030	VIL	Input Low Voltage I/O ports MCLR (Schmitt Trigger) T0CKI (Schmitt Trigger) OSC1 (Schmitt Trigger) OSC1	Vss Vss Vss Vss Vss Vss		0.2 VDD 0.15 VDD 0.15 VDD 0.15 VDD 0.3 VDD	V V V V	Pin at hi-impedance RC mode only ⁽³⁾ XT, HS and LP modes	
D040	VIH	Input High Voltage I/O ports I/O ports MCLR (Schmitt Trigger) T0CKI (Schmitt Trigger) OSC1 (Schmitt Trigger) OSC1	0.2 VDD + 1 2.0 0.85 VDD 0.85 VDD 0.85 VDD 0.85 VDD 0.7 VDD		VDD VDD VDD VDD VDD VDD VDD	V V V V V V	For all V _{DD} ⁽⁴⁾ 4.0V < V _{DD} ≤ 5.5V ⁽⁴⁾ RC mode only ⁽³⁾ XT, HS and LP modes	
D050	VHYS	Hysteresis of Schmitt Trigger inputs	0.15 Vdd*	_	—	V		
D060	IIL	Input Leakage Current ^(1,2) I/O ports MCLR MCLR TOCKI OSC1	-1.0 -5.0 -3.0 -3.0	0.5 0.5 0.5 0.5	+1.0 +5.0 +3.0 +3.0 —	μΑ μΑ μΑ μΑ μΑ	For VDD \leq 5.5V: VSS \leq VPIN \leq VDD, pin at hi-impedance VPIN = VSS +0.25V VPIN = VDD VSS \leq VPIN \leq VDD VSS \leq VPIN \leq VDD, XT, HS and LP modes	
D080	VOL	Output Low Voltage I/O ports OSC2/CLKOUT		_	0.6 0.6	V V	IOL = 8.7 mA, VDD = 4.5 V IOL = 1.6 mA, VDD = 4.5 V, RC mode only	
	VOH	Output High Voltage ⁽²⁾ I/O ports OSC2/CLKOUT	Vdd - 0.7 Vdd - 0.7			V V	IOH = -5.4 mA, VDD = 4.5V IOH = -1.0 mA, VDD = 4.5V, RC mode only	

These parameters are characterized but not tested.

† Data in the Typical ("Typ") column is based on characterization results at 25°C. This data is for design guidance only and is not tested.

Note 1: The leakage current on the MCLR/VPP pin is strongly dependent on the applied voltage level. The specified levels represent normal operating conditions. Higher leakage current may be measured at different input voltage.

2: Negative current is defined as coming out of the pin.

3: For the RC mode, the OSC1/CLKIN pin is a Schmitt Trigger input. It is not recommended that the PIC16C5X be driven with external clock in RC mode.

*



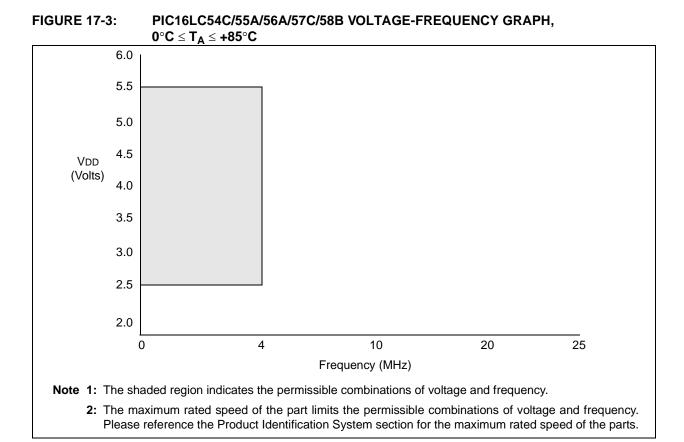
TABLE 16-2:INPUT CAPACITANCE FOR
PIC16C54A/C58A

Pin	Typical Capacitance (pF)			
FIII	18L PDIP	18L SOIC		
RA port	5.0	4.3		
RB port	5.0	4.3		
MCLR	17.0	17.0		
OSC1	4.0	3.5		
OSC2/CLKOUT	4.3	3.5		
TOCKI	3.2	2.8		

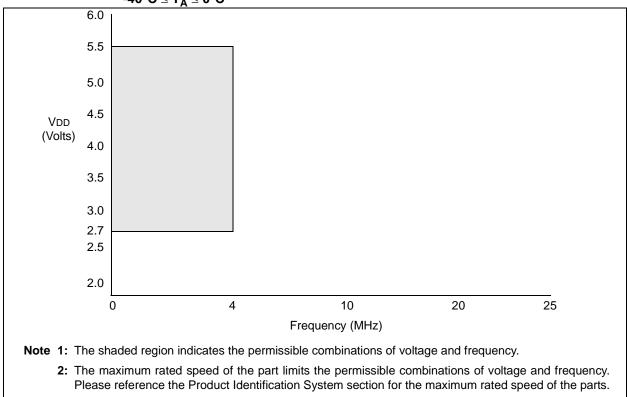
All capacitance values are typical at 25°C. A part-to-part variation of $\pm 25\%$ (three standard deviations) should be taken into account.

FIGURE 16-23: PORTA, B AND C IOL vs. VOL, VDD = 5V









17.4 Timing Parameter Symbology and Load Conditions

The timing parameter symbols have been created with one of the following formats:

1. TppS2ppS

2. Tp	2. TppS							
Т								
F	Frequency	T Time						
Lowe	Lowercase letters (pp) and their meanings:							
рр								
2	to	mc MCLR						
ck	CLKOUT	osc oscillator						
су	cycle time	os OSC1						
drt	device reset timer	t0 T0CKI						
io	I/O port	wdt watchdog timer						
Uppe	Uppercase letters and their meanings:							
S								
F	Fall	P Period						
н	High	R Rise						
T	Invalid (Hi-impedance)	V Valid						
L	Low	Z Hi-impedance						

FIGURE 17-5: LOAD CONDITIONS FOR DEVICE TIMING SPECIFICATIONS -PIC16C54C/CR54C/C55A/C56A/CR56A/C57C/CR57C/C58B/CR58B-04, 20



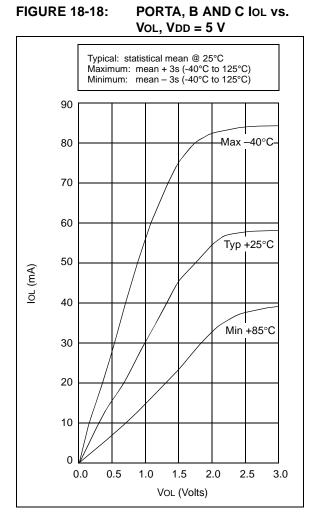


TABLE 18-2:INPUT CAPACITANCE

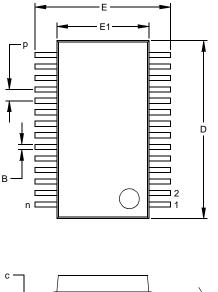
Pin	Typical Capacitance (pF)			
Pin	18L PDIP	18L SOIC		
RA port	5.0	4.3		
RB port	5.0	4.3		
MCLR	17.0	17.0		
OSC1	4.0	3.5		
OSC2/CLKOUT	4.3	3.5		
тоскі	3.2	2.8		

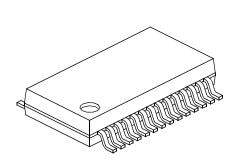
All capacitance values are typical at 25° C. A part-to-part variation of ±25% (three standard deviations) should be taken into account.

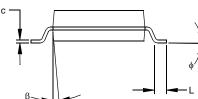
NOTES:

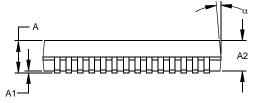
28-Lead Plastic Shrink Small Outline (SS) - 209 mil, 5.30 mm (SSOP)

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging









	Units			INCHES			MILLIMETERS*		
Dimensio	MIN	NOM	MAX	MIN	NOM	MAX			
Number of Pins	n		28			28			
Pitch	р		.026			0.65			
Overall Height	А	.068	.073	.078	1.73	1.85	1.98		
Molded Package Thickness	A2	.064	.068	.072	1.63	1.73	1.83		
Standoff §	A1	.002	.006	.010	0.05	0.15	0.25		
Overall Width	Е	.299	.309	.319	7.59	7.85	8.10		
Molded Package Width	E1	.201	.207	.212	5.11	5.25	5.38		
Overall Length	D	.396	.402	.407	10.06	10.20	10.34		
Foot Length	L	.022	.030	.037	0.56	0.75	0.94		
Lead Thickness	С	.004	.007	.010	0.10	0.18	0.25		
Foot Angle	¢	0	4	8	0.00	101.60	203.20		
Lead Width	В	.010	.013	.015	0.25	0.32	0.38		
Mold Draft Angle Top	α	0	5	10	0	5	10		
Mold Draft Angle Bottom	β	0	5	10	0	5	10		

* Controlling Parameter § Significant Characteristic

Notes:

Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed .010" (0.254mm) per side.

JEDEC Equivalent: MS-150 Drawing No. C04-073

APPENDIX A: COMPATIBILITY

To convert code written for PIC16CXX to PIC16C5X, the user should take the following steps:

- 1. Check any CALL, GOTO or instructions that modify the PC to determine if any program memory page select operations (PA2, PA1, PA0 bits) need to be made.
- 2. Revisit any computed jump operations (write to PC or add to PC, etc.) to make sure page bits are set properly under the new scheme.
- 3. Eliminate any special function register page switching. Redefine data variables to reallocate them.
- 4. Verify all writes to STATUS, OPTION, and FSR registers since these have changed.
- 5. Change RESET vector to proper value for processor used.
- 6. Remove any use of the ADDLW, RETURN and SUBLW instructions.
- 7. Rewrite any code segments that use interrupts.

APPENDIX B: REVISION HISTORY

Revision KE (January 2013)

Added a note to each package outline drawing.